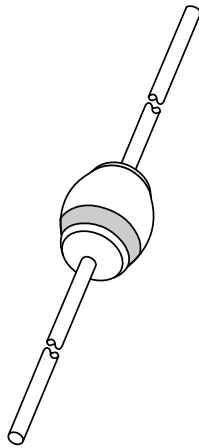


DATA SHEET



BYV27 series Ultra fast low-loss controlled avalanche rectifiers

Product specification
Supersedes data of 1996 Oct 02

1997 Nov 24

Ultra fast low-loss controlled avalanche rectifiers

BYV27 series

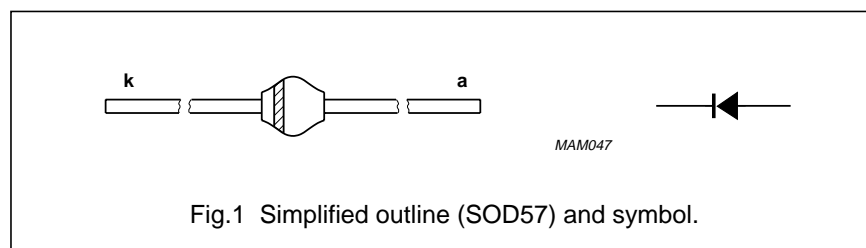
FEATURES

- Glass passivated
- High maximum operating temperature
- Low leakage current
- Excellent stability
- Guaranteed avalanche energy absorption capability
- Available in ammo-pack.

DESCRIPTION

Rugged glass SOD57 package, using a high temperature alloyed construction.

This package is hermetically sealed and fatigue free as coefficients of expansion of all used parts are matched.



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|-------------|---------------------------------|--|------|------|------|
| V_{RRM} | repetitive peak reverse voltage | | | | |
| | BYV27-50 | | – | 50 | V |
| | BYV27-100 | | – | 100 | V |
| | BYV27-150 | | – | 150 | V |
| | BYV27-200 | | – | 200 | V |
| | BYV27-300 | | – | 300 | V |
| | BYV27-400 | | – | 400 | V |
| | BYV27-500 | | – | 500 | V |
| | BYV27-600 | | – | 600 | V |
| V_R | continuous reverse voltage | | | | |
| | BYV27-50 | | – | 50 | V |
| | BYV27-100 | | – | 100 | V |
| | BYV27-150 | | – | 150 | V |
| | BYV27-200 | | – | 200 | V |
| | BYV27-300 | | – | 300 | V |
| | BYV27-400 | | – | 400 | V |
| | BYV27-500 | | – | 500 | V |
| | BYV27-600 | | – | 600 | V |
| $I_{F(AV)}$ | average forward current | $T_{tp} = 85\text{ °C}$; lead length = 10 mm; see Figs 2, 3 and 4; | | | |
| | BYV27-50 to 200 | averaged over any 20 ms period; | – | 2.0 | A |
| | BYV27-300 and 400 | see also Figs 14, 15 and 16 | – | 1.9 | A |
| | BYV27-500 and 600 | | – | 1.6 | A |
| $I_{F(AV)}$ | average forward current | $T_{amb} = 60\text{ °C}$; printed-circuit board mounting (see Fig. 25); | | | |
| | BYV27-50 to 200 | see Figs 5, 6 and 7; | – | 1.30 | A |
| | BYV27-300 and 400 | averaged over any 20 ms period; | – | 1.25 | A |
| | BYV27-500 and 600 | see also Figs 14, 15 and 16 | – | 1.10 | A |

Ultra fast low-loss controlled avalanche rectifiers

BYV27 series

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|-----------|--|--|------|------|------|
| I_{FRM} | repetitive peak forward current | $T_{tp} = 85\text{ °C}$; see Figs 8, 9 and 10 | – | 20 | A |
| | BYV27-50 to 400 | | | 16 | A |
| I_{FRM} | repetitive peak forward current | $T_{amb} = 60\text{ °C}$; see Figs 11, 12 and 13 | – | 14 | A |
| | BYV27-50 to 200 | | | 13 | A |
| | BYV27-300 and 400 BYV27-500 and 600 | | | 11 | A |
| I_{FSM} | non-repetitive peak forward current | $t = 10\text{ ms}$ half sine wave; $T_j = T_{j\text{ max}}$ prior to surge; $V_R = V_{RRM\text{ max}}$ | – | 50 | A |
| | BYV27-50 to 400 BYV27-500 and 600 | | | 40 | A |
| E_{RSM} | non-repetitive peak reverse avalanche energy | $L = 120\text{ mH}$; $T_j = T_{j\text{ max}}$ prior to surge; inductive load switched off | – | 20 | mJ |
| T_{stg} | storage temperature | | –65 | +175 | °C |
| T_j | junction temperature | see Fig. 17 | –65 | +175 | °C |

ELECTRICAL CHARACTERISTICS

$T_j = 25\text{ °C}$ unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT | | | |
|-------------|--|---|------|------|------|------------|---|---|---|
| V_F | forward voltage | $I_F = 2\text{ A}$; $T_j = T_{j\text{ max}}$; see Figs 18, 19 and 20 | – | – | 0.78 | V | | | |
| | BYV27-50 to 200 | | | | 0.82 | V | | | |
| | BYV27-300 and 400 BYV27-500 and 600 | | | | 1.00 | V | | | |
| V_F | forward voltage | $I_F = 2\text{ A}$; see Figs 18, 19 and 20 | – | – | 0.98 | V | | | |
| | BYV27-50 to 200 | | | | 1.05 | V | | | |
| | BYV27-300 and 400 BYV27-500 and 600 | | | | 1.25 | V | | | |
| $V_{(BR)R}$ | reverse avalanche breakdown voltage | $I_R = 0.1\text{ mA}$ | | | | | | | |
| | BYV27-50 | | | | | 55 | – | – | V |
| | BYV27-100 | | | | | 110 | – | – | V |
| | BYV27-150 | | | | | 165 | – | – | V |
| | BYV27-200 | | | | | 220 | – | – | V |
| | BYV27-300 | | | | | 330 | – | – | V |
| | BYV27-400 | | | | | 440 | – | – | V |
| | BYV27-500 BYV27-600 | | | | | 560 675 | – | – | V |
| I_R | reverse current | $V_R = V_{RRM\text{ max}}$; see Fig. 21 | – | – | 5 | μA | | | |
| | | $V_R = V_{RRM\text{ max}}$; $T_j = 165\text{ °C}$; see Fig. 21 | – | – | 150 | μA | | | |

Ultra fast low-loss controlled avalanche rectifiers

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| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT | |
|----------------------------------|---|---|------|------|-------------------|------------|----|
| t_{rr} | reverse recovery time | when switched from $I_F = 0.5$ A to $I_R = 1$ A; measured at $I_R = 0.25$ A; see Fig. 27 | – | – | 25 | ns | |
| | BYV27-50 to 200 | | | | 50 | ns | |
| C_d | diode capacitance | $f = 1$ MHz; $V_R = 0$; see Figs 22, 23 and 24 | – | 100 | – | pF | |
| | BYV27-50 to 200 | | | | | 80 | pF |
| | BYV27-300 and 400 | | | | | 65 | pF |
| $\left \frac{dI_R}{dt} \right $ | maximum slope of reverse recovery current | when switched from $I_F = 1$ A to $V_R \geq 30$ V and $dI_F/dt = -1$ A/ μ s; see Fig. 26 | – | – | 4 | A/ μ s | |
| | | | | | BYV27-500 and 600 | | |

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
|----------------|---|---------------------|-------|------|
| $R_{th\ j-tp}$ | thermal resistance from junction to tie-point | lead length = 10 mm | 46 | K/W |
| $R_{th\ j-a}$ | thermal resistance from junction to ambient | note 1 | 100 | K/W |

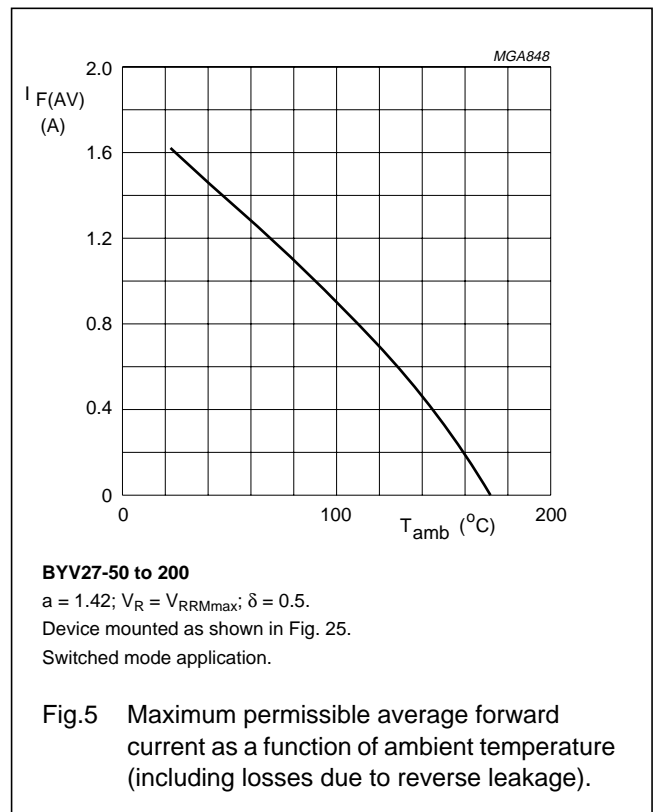
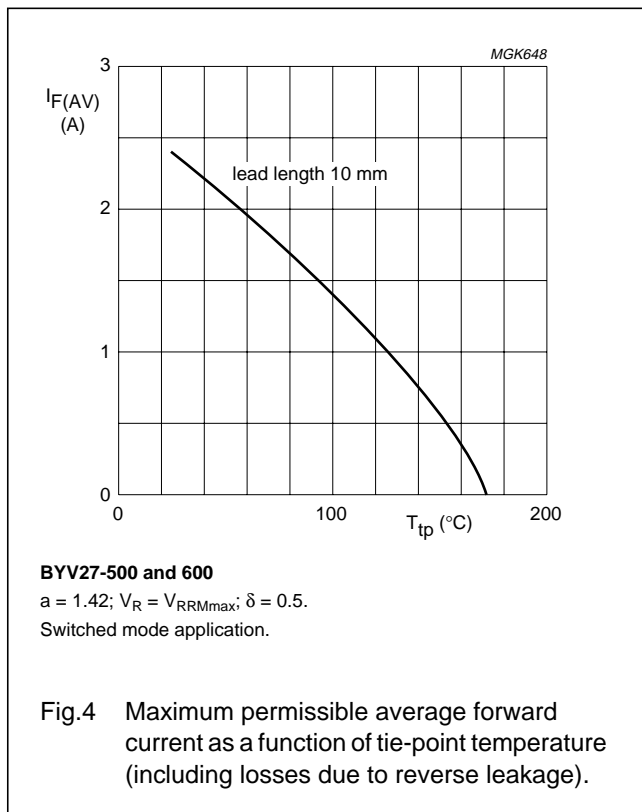
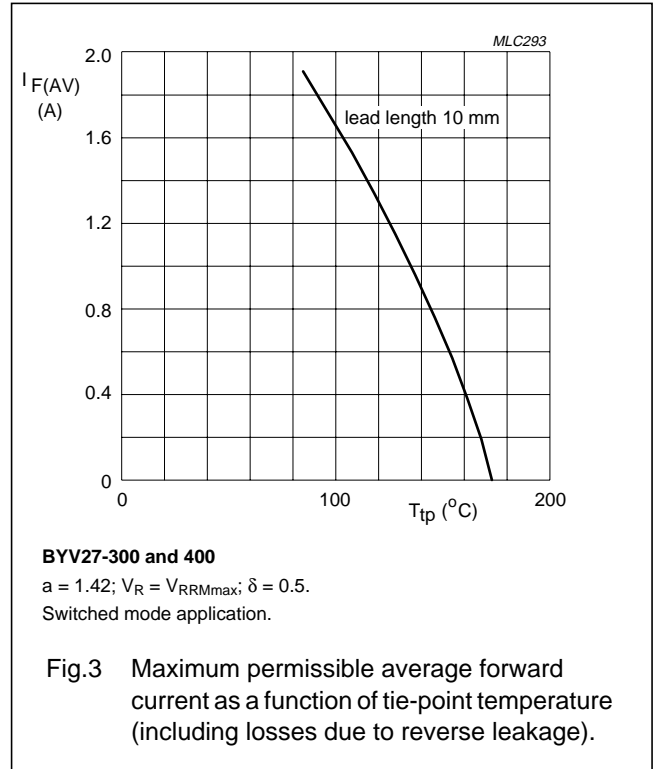
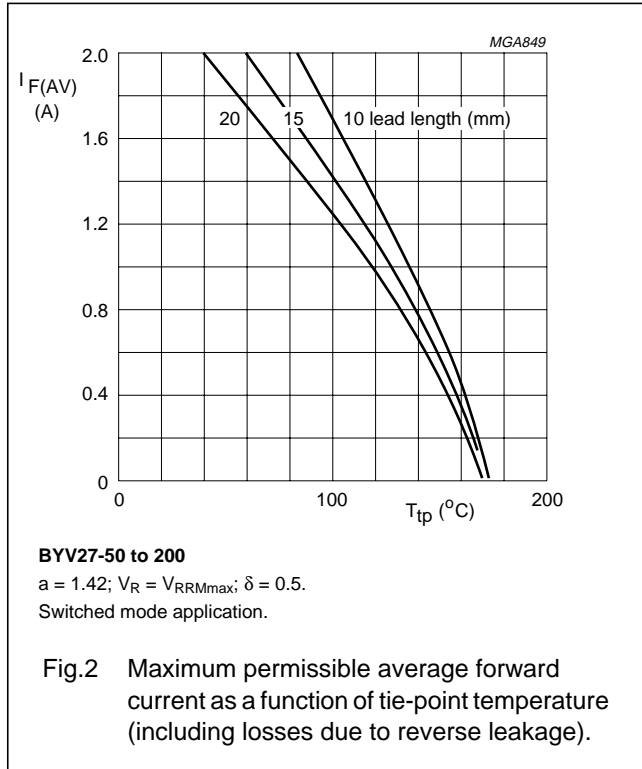
Note

1. Device mounted on an epoxy-glass printed-circuit board, 1.5 mm thick; thickness of Cu-layer ≥ 40 μ m, see Fig. 25. For more information please refer to the "General Part of associated Handbook".

Ultra fast low-loss
controlled avalanche rectifiers

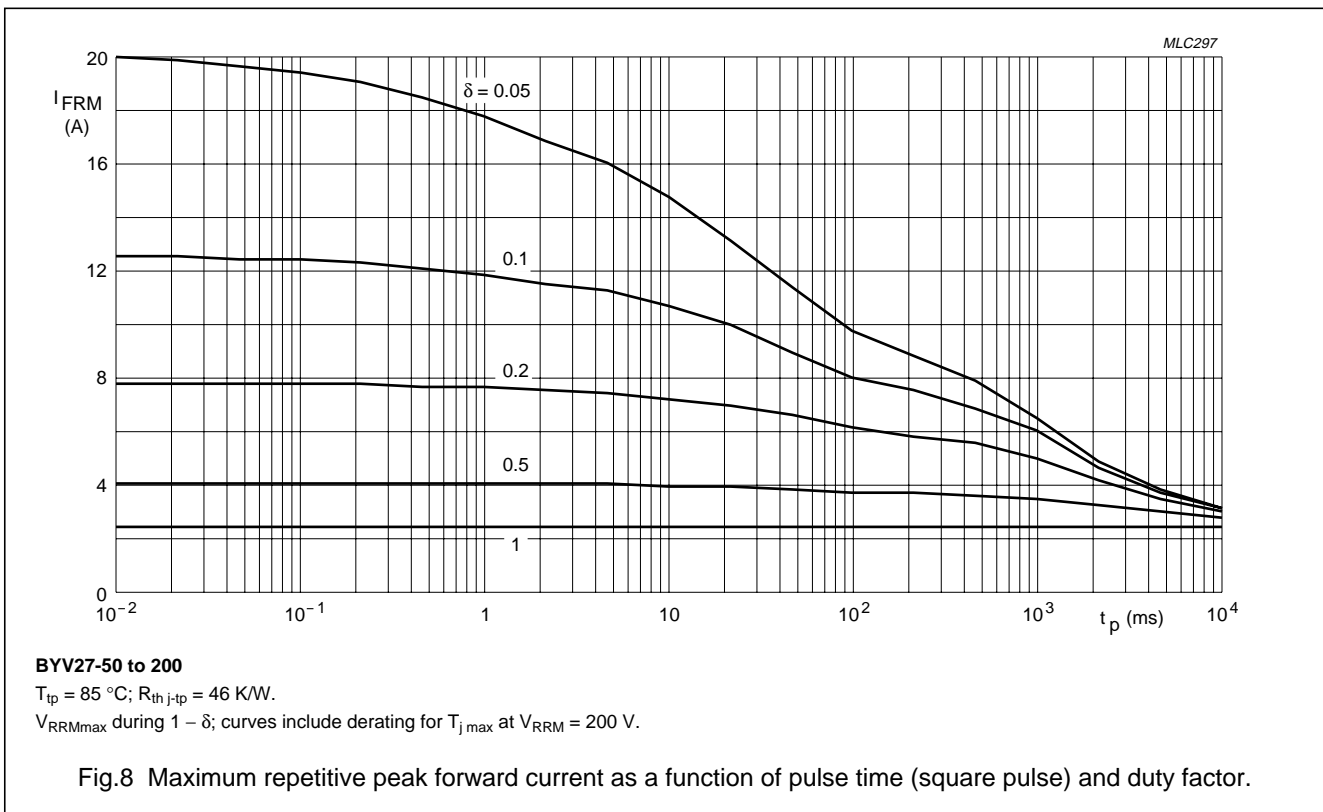
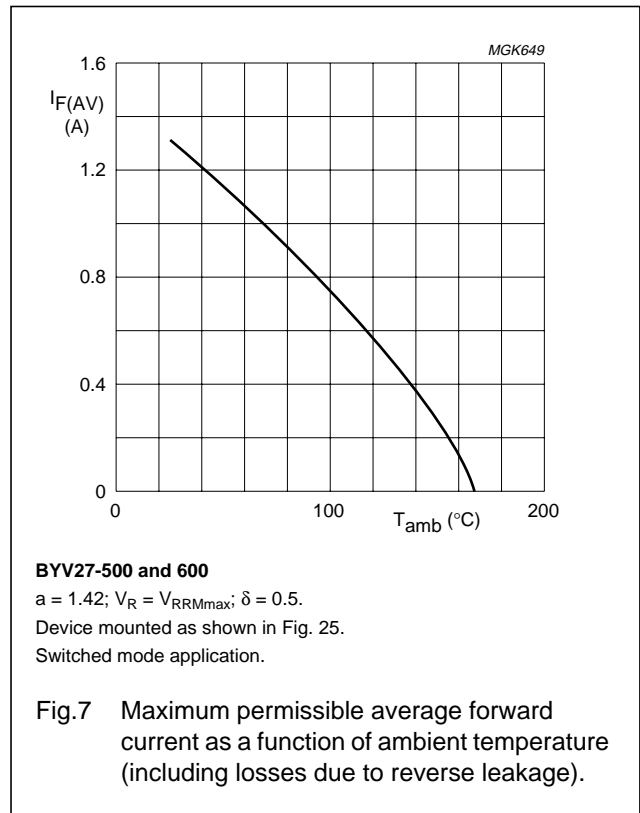
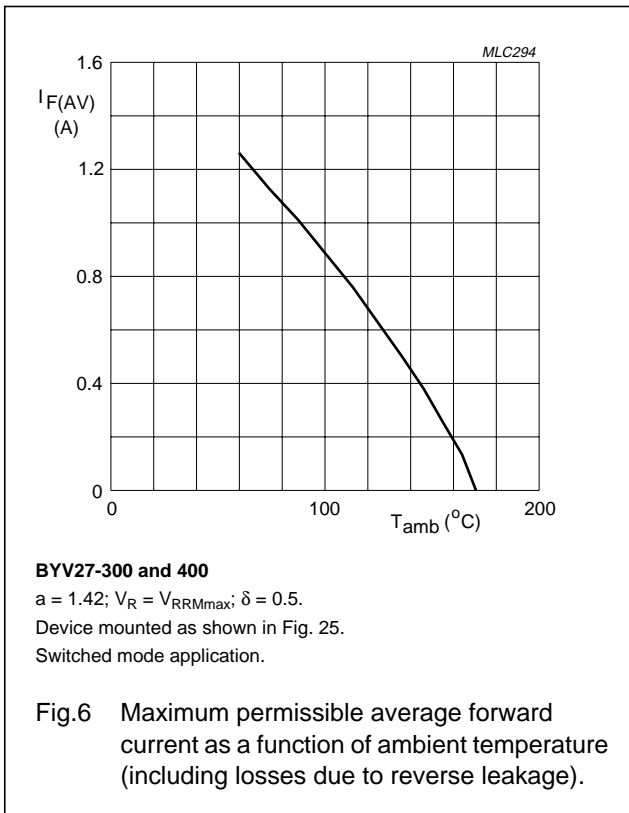
BYV27 series

GRAPHICAL DATA



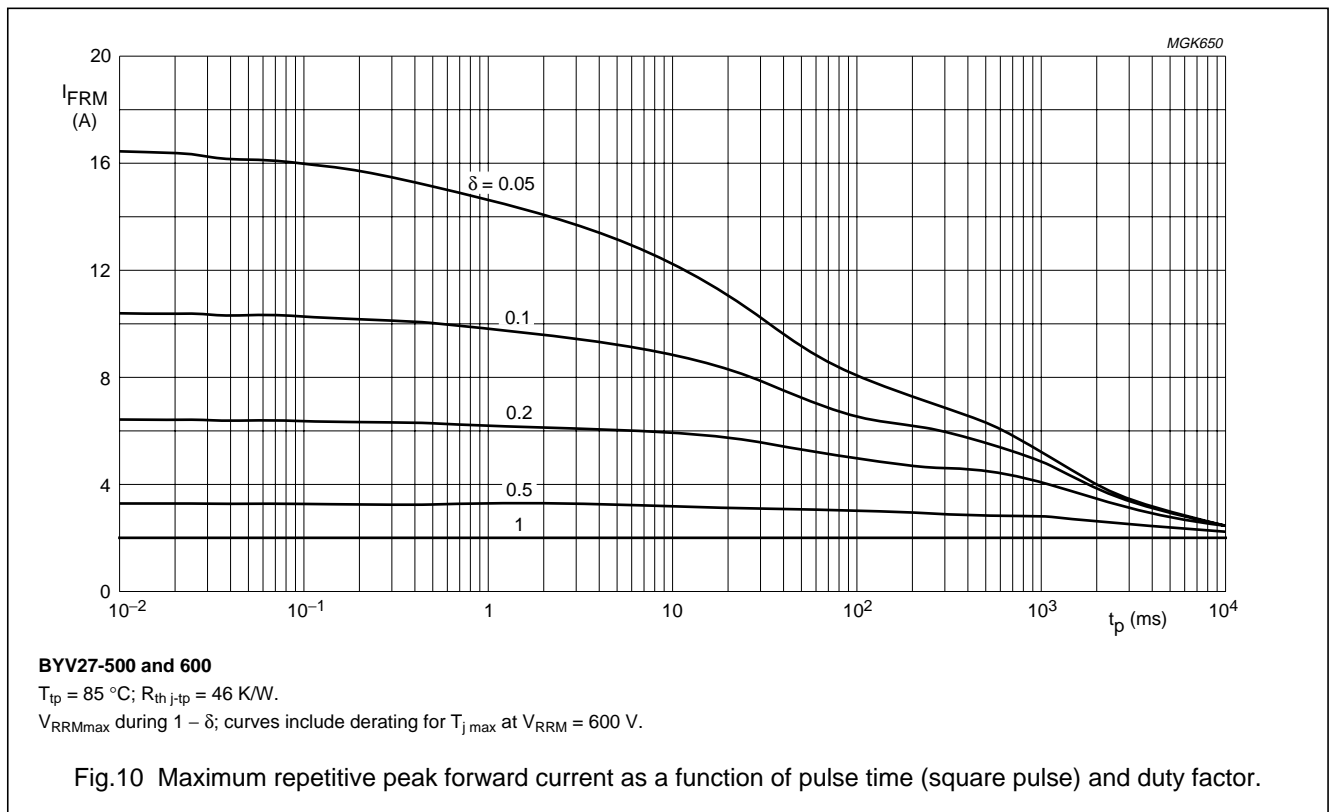
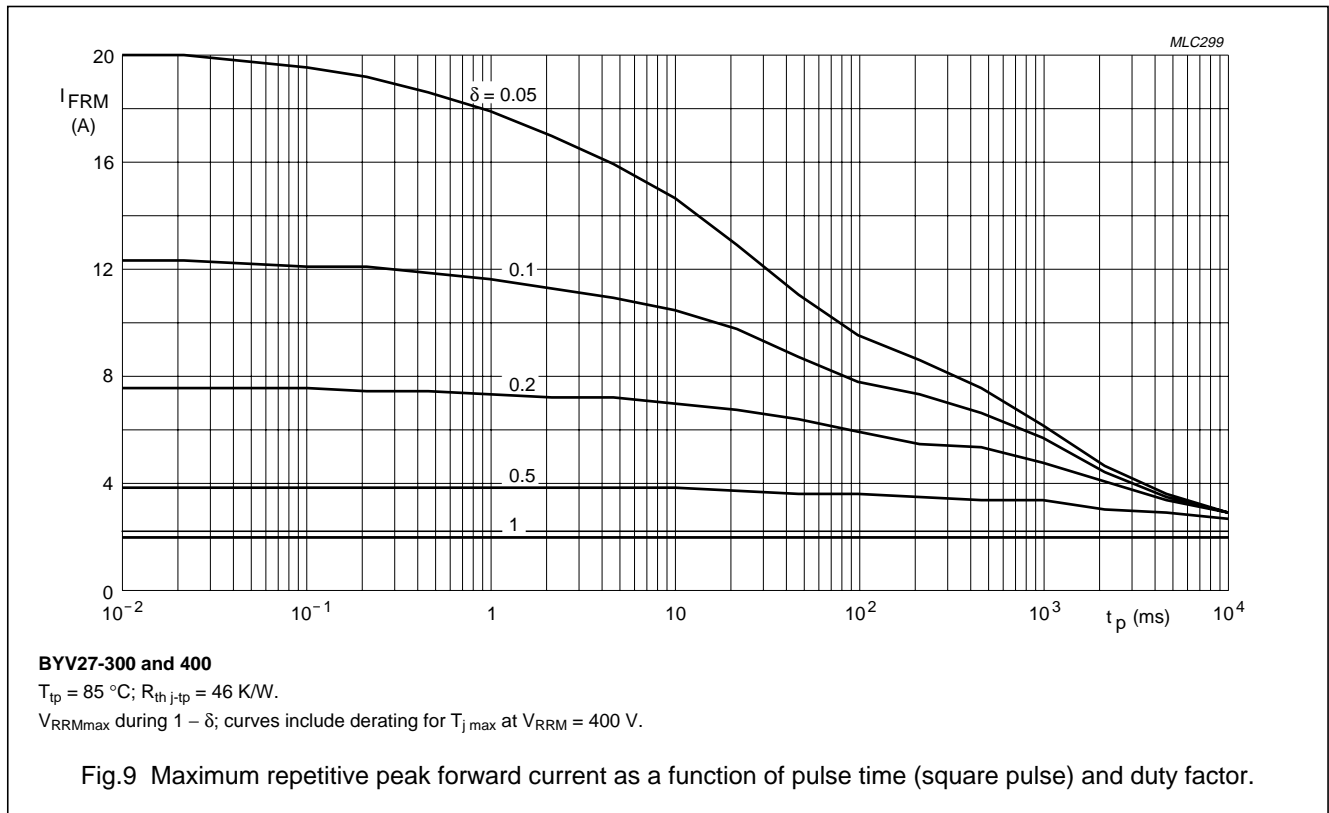
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BYV27 series



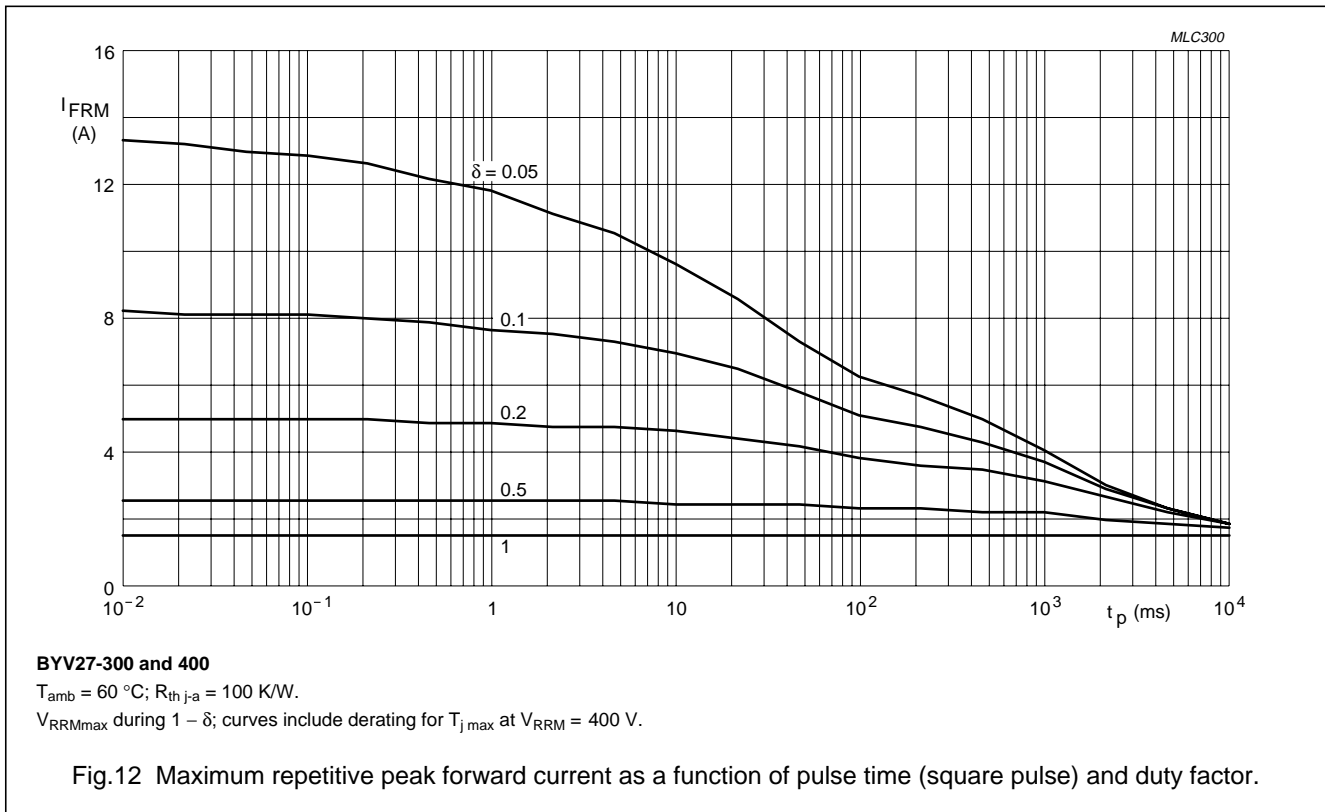
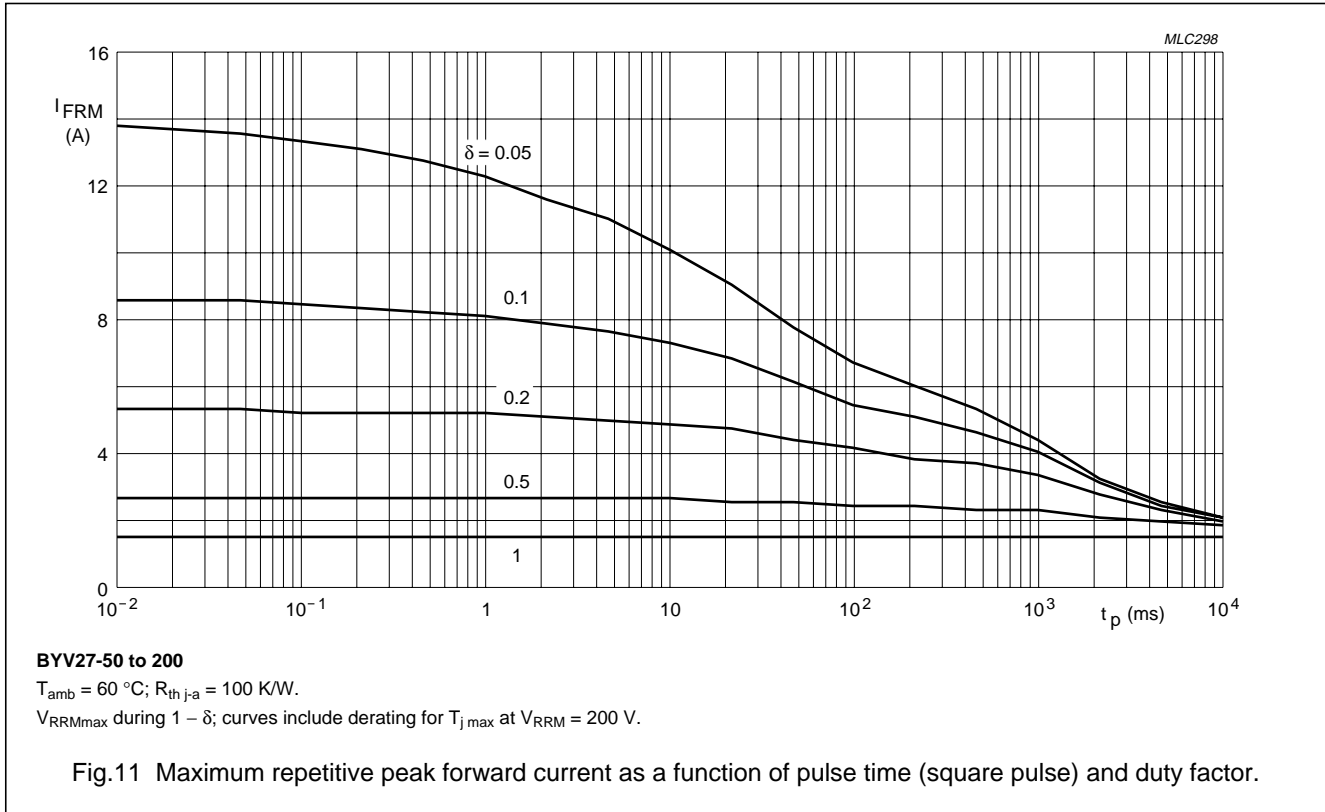
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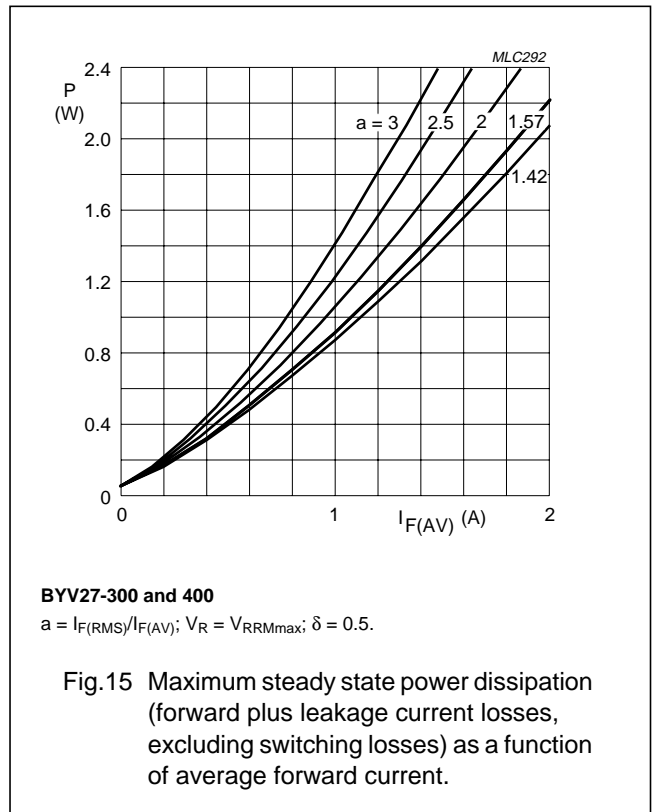
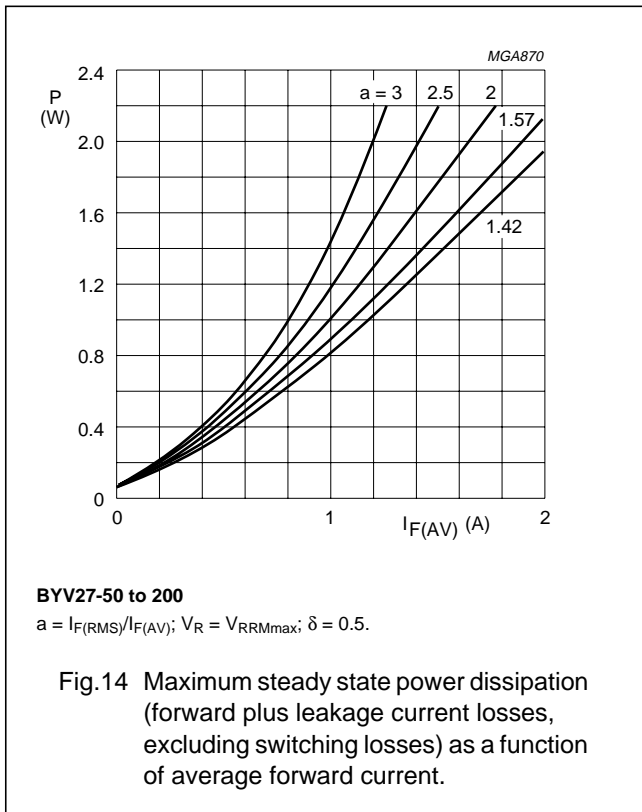
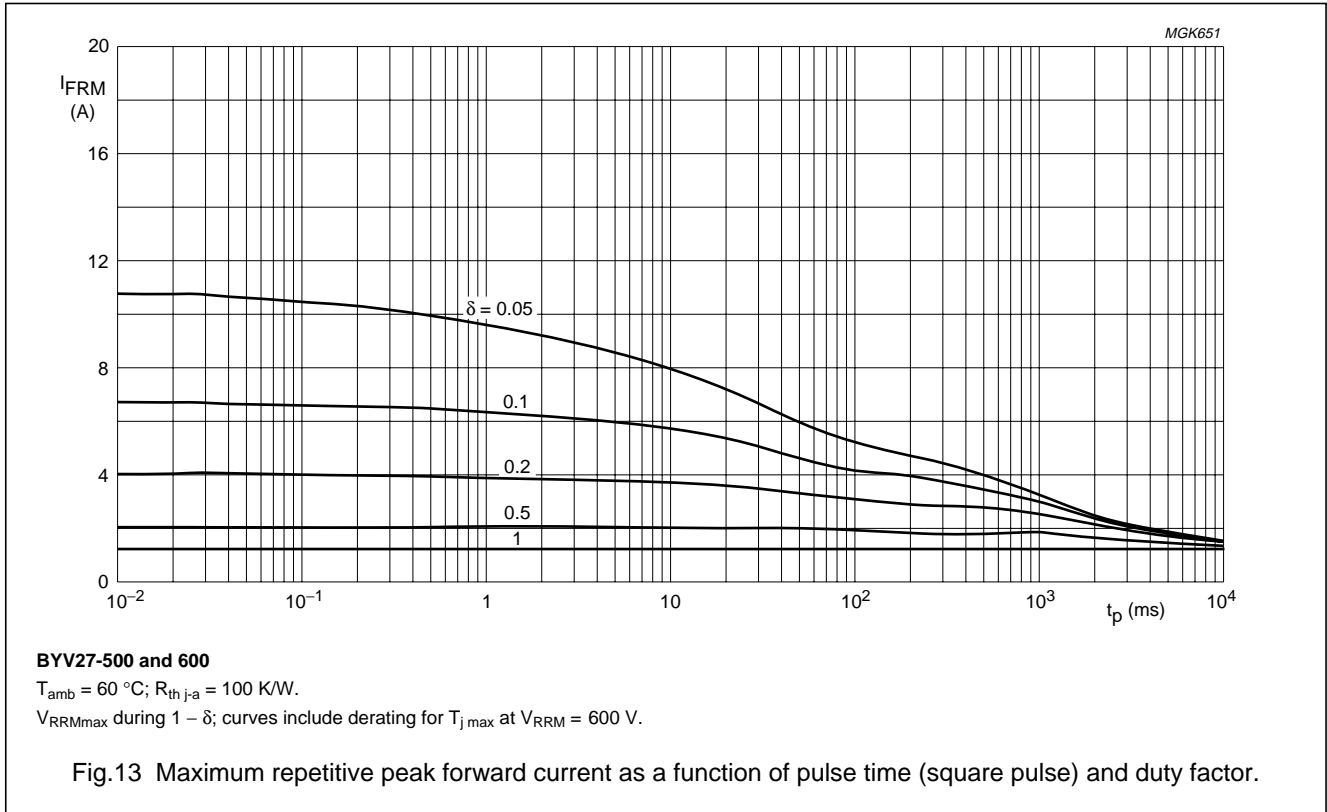
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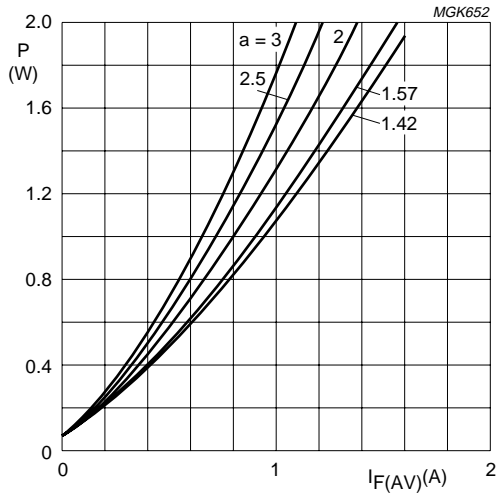
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controlled avalanche rectifiers

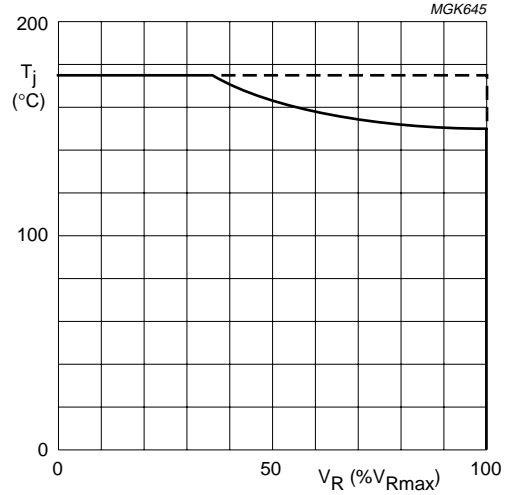
BYV27 series



BYV27-500 and 600

$a = I_{F(RMS)}/I_{F(AV)}$; $V_R = V_{RRMmax}$; $\delta = 0.5$.

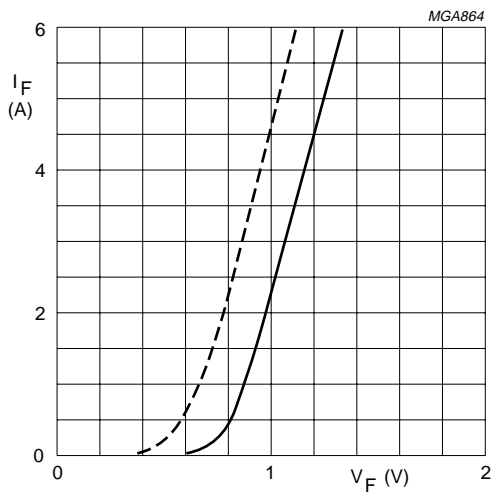
Fig. 16 Maximum steady state power dissipation (forward plus leakage current losses, excluding switching losses) as a function of average forward current.



Solid line = V_R .

Dotted line = V_{RRM} ; $\delta = 0.5$.

Fig. 17 Maximum permissible junction temperature as a function of maximum reverse voltage percentage.

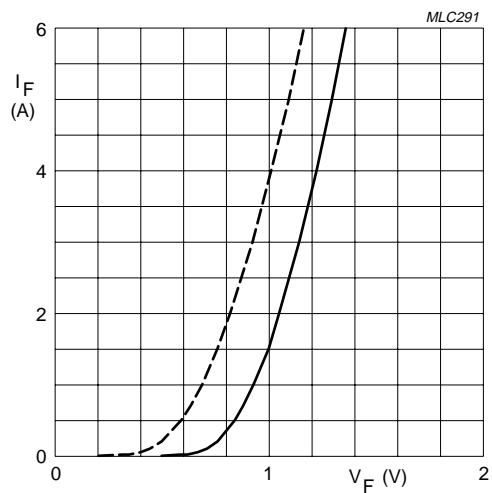


BYV27-50 to 200

Dotted line: $T_j = 175$ °C.

Solid line: $T_j = 25$ °C.

Fig. 18 Forward current as a function of forward voltage; maximum values.



BYV27-300 and 400

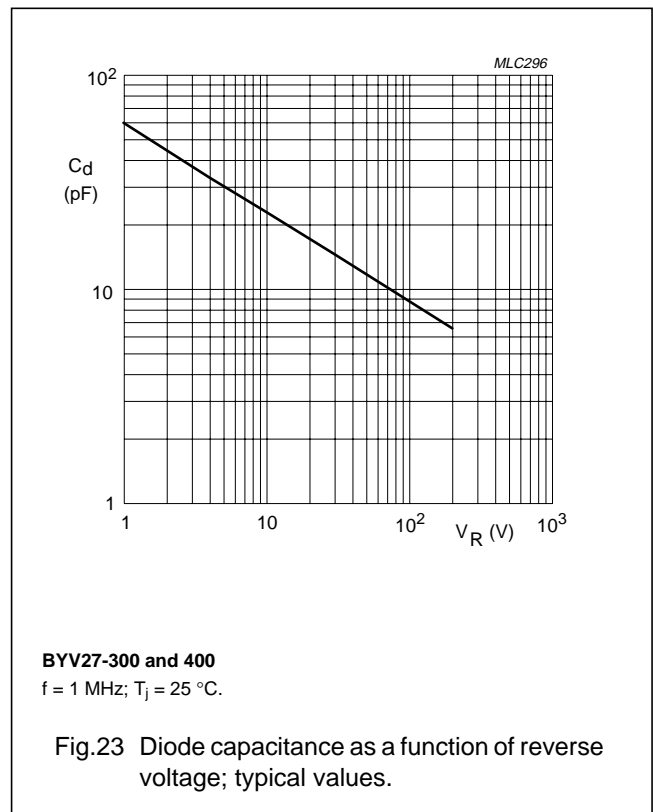
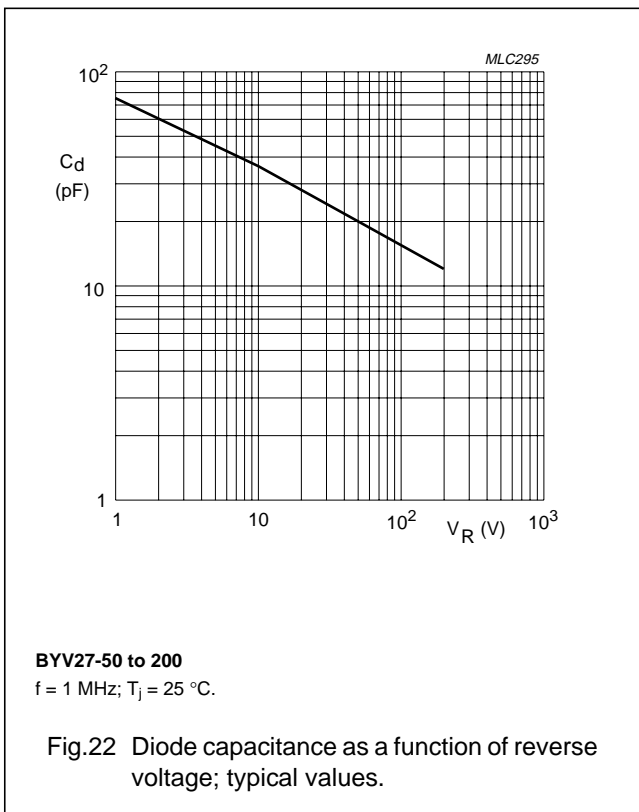
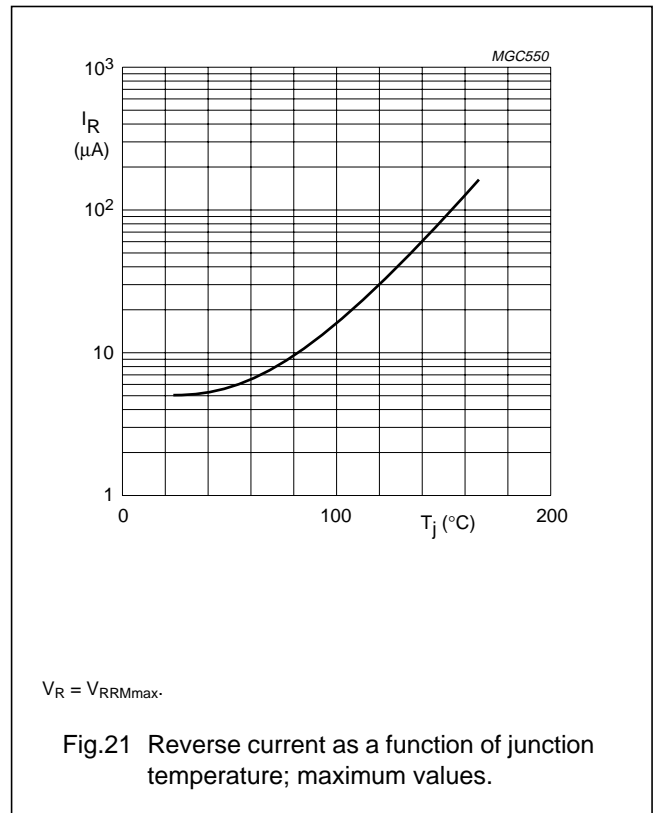
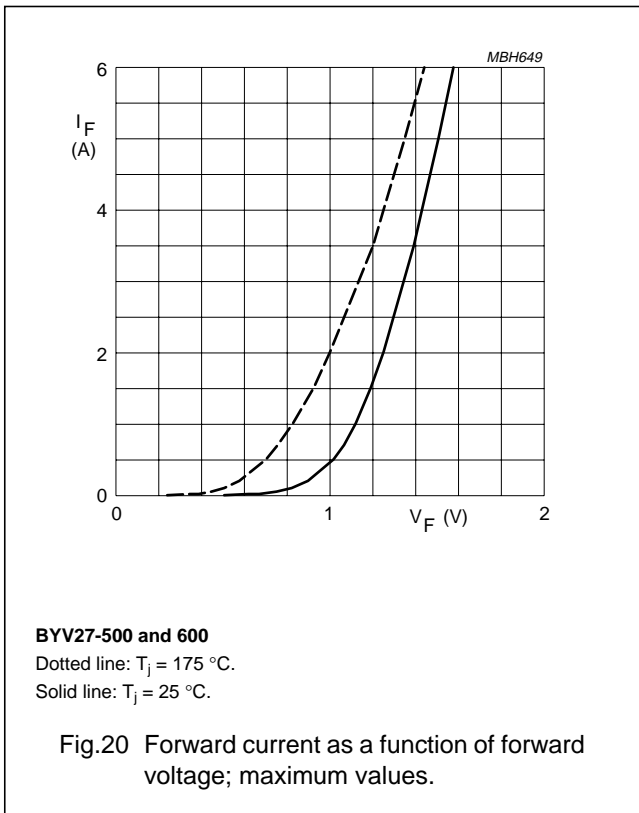
Dotted line: $T_j = 175$ °C.

Solid line: $T_j = 25$ °C.

Fig. 19 Forward current as a function of forward voltage; maximum values.

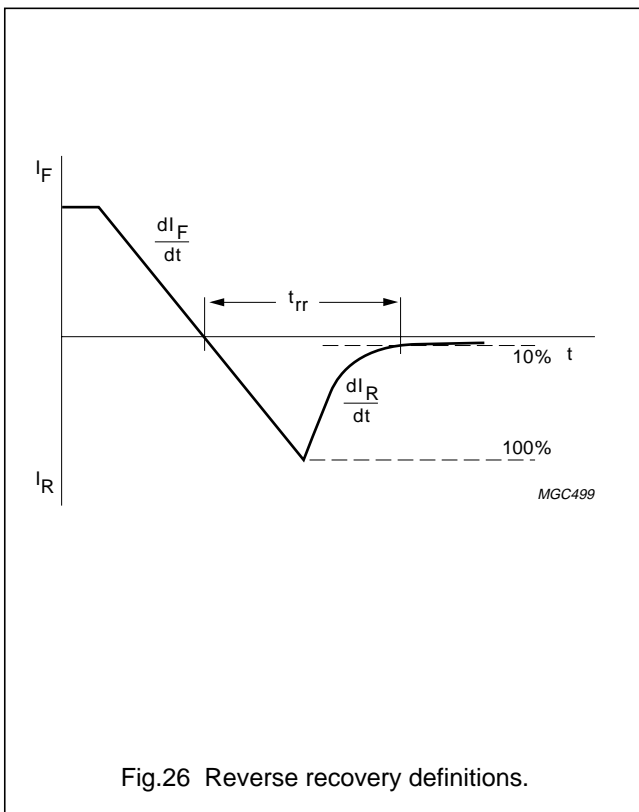
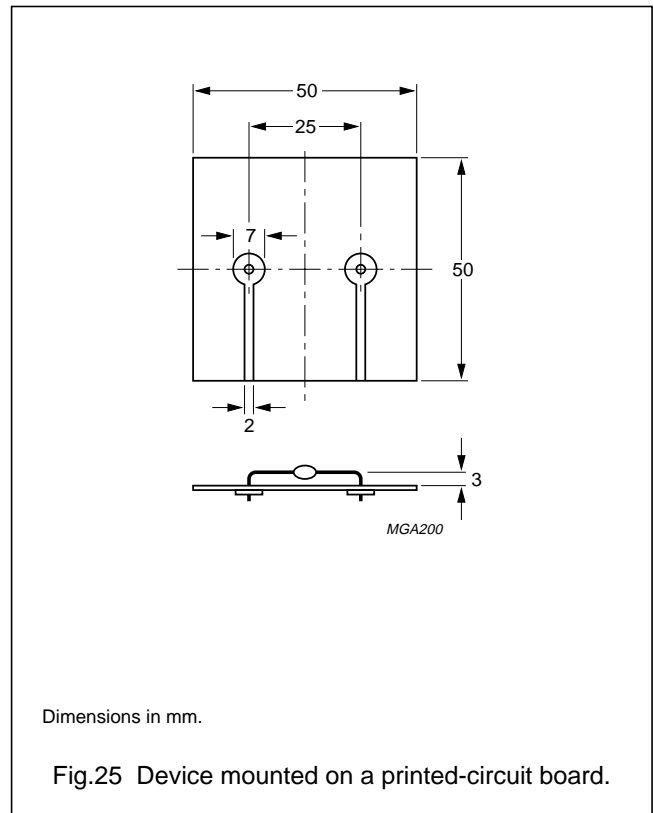
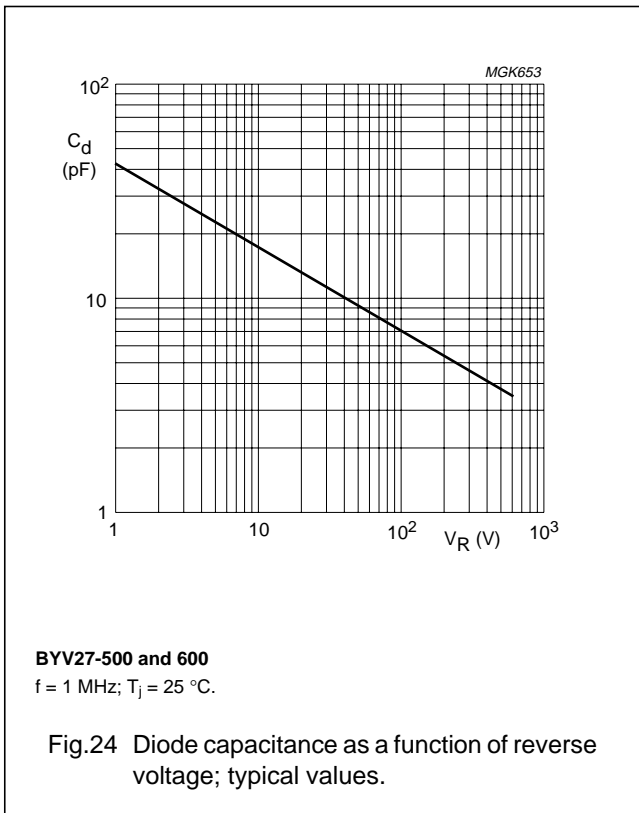
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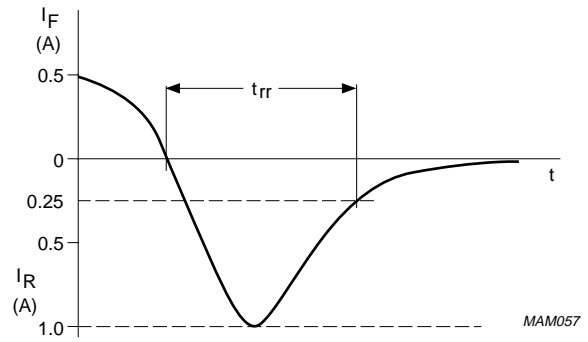
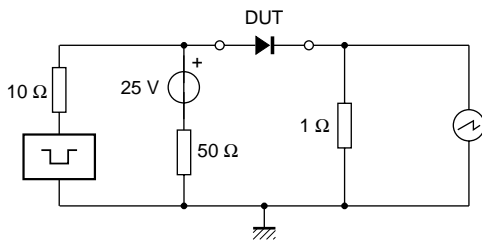
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Ultra fast low-loss controlled avalanche rectifiers

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Input impedance oscilloscope: 1 MΩ, 22 pF; $t_r \leq 7$ ns.
Source impedance: 50 Ω; $t_r \leq 15$ ns.

Fig.27 Test circuit and reverse recovery time waveform and definition.

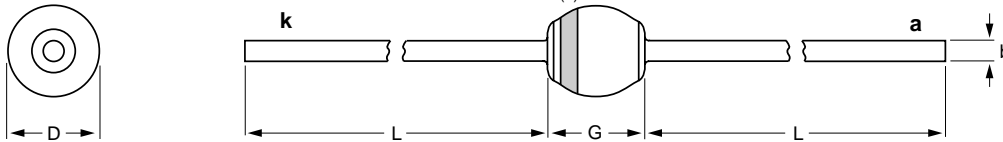
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PACKAGE OUTLINE

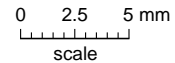
Hermetically sealed glass package; axial leaded; 2 leads

SOD57



DIMENSIONS (mm are the original dimensions)

| UNIT | b max. | D max. | G max. | L min. |
|------|-----------|-----------|-----------|-----------|
| mm | 0.81 | 3.81 | 4.57 | 28 |



Note

1. The marking band indicates the cathode.

| OUTLINE VERSION | REFERENCES | | | EUROPEAN PROJECTION | ISSUE DATE |
|--------------------|------------|-------|------|------------------------|------------|
| | IEC | JEDEC | EIAJ | | |
| SOD57 | | | | | 97-10-14 |

DEFINITIONS

| Data Sheet Status | |
|---|---|
| Objective specification | This data sheet contains target or goal specifications for product development. |
| Preliminary specification | This data sheet contains preliminary data; supplementary data may be published later. |
| Product specification | This data sheet contains final product specifications. |
| Limiting values | |
| Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability. | |
| Application information | |
| Where application information is given, it is advisory and does not form part of the specification. | |

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Philips Semiconductors – a worldwide company

Argentina: see South America

Australia: 34 Waterloo Road, NORTH RYDE, NSW 2113,
Tel. +61 2 9805 4455, Fax. +61 2 9805 4466

Austria: Computerstr. 6, A-1101 WIEN, P.O. Box 213, Tel. +43 160 1010,
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Belarus: Hotel Minsk Business Center, Bld. 3, r. 1211, Volodarski Str. 6,
220050 MINSK, Tel. +375 172 200 733, Fax. +375 172 200 773

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Tel. +359 2 689 211, Fax. +359 2 689 102

Canada: PHILIPS SEMICONDUCTORS/COMPONENTS,
Tel. +1 800 234 7381

China/Hong Kong: 501 Hong Kong Industrial Technology Centre,
72 Tat Chee Avenue, Kowloon Tong, HONG KONG,
Tel. +852 2319 7888, Fax. +852 2319 7700

Colombia: see South America

Czech Republic: see Austria

Denmark: Prags Boulevard 80, PB 1919, DK-2300 COPENHAGEN S,
Tel. +45 32 88 2636, Fax. +45 31 57 0044

Finland: Sinikalliontie 3, FIN-02630 ESPOO,
Tel. +358 9 615800, Fax. +358 9 61580920

France: 51 Rue Carnot, BP317, 92156 SURESNES Cedex,
Tel. +33 1 40 99 6161, Fax. +33 1 40 99 6427

Germany: Hammerbrookstraße 69, D-20097 HAMBURG,
Tel. +49 40 23 53 60, Fax. +49 40 23 536 300

Greece: No. 15, 25th March Street, GR 17778 TAVROS/ATHENS,
Tel. +30 1 4894 339/239, Fax. +30 1 4814 240

Hungary: see Austria

India: Philips INDIA Ltd, Band Box Building, 2nd floor,
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Tel. +91 22 493 8541, Fax. +91 22 493 0966

Indonesia: see Singapore

Ireland: Newstead, Clonskeagh, DUBLIN 14,
Tel. +353 1 7640 000, Fax. +353 1 7640 200

Israel: RAPAC Electronics, 7 Kehilat Saloniki St, PO Box 18053,
TEL AVIV 61180, Tel. +972 3 645 0444, Fax. +972 3 649 1007

Italy: PHILIPS SEMICONDUCTORS, Piazza IV Novembre 3,
20124 MILANO, Tel. +39 2 6752 2531, Fax. +39 2 6752 2557

Japan: Philips Bldg 13-37, Kohnan 2-chome, Minato-ku, TOKYO 108,
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Korea: Philips House, 260-199 Itaewon-dong, Yongsan-ku, SEOUL,
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Malaysia: No. 76 Jalan Universiti, 46200 PETALING JAYA, SELANGOR,
Tel. +60 3 750 5214, Fax. +60 3 757 4880

Mexico: 5900 Gateway East, Suite 200, EL PASO, TEXAS 79905,
Tel. +9-5 800 234 7381

Middle East: see Italy

Netherlands: Postbus 90050, 5600 PB EINDHOVEN, Bldg. VB,
Tel. +31 40 27 82785, Fax. +31 40 27 88399

New Zealand: 2 Wagener Place, C.P.O. Box 1041, AUCKLAND,
Tel. +64 9 849 4160, Fax. +64 9 849 7811

Norway: Box 1, Manglerud 0612, OSLO,
Tel. +47 22 74 8000, Fax. +47 22 74 8341

Philippines: Philips Semiconductors Philippines Inc.,
106 Valero St. Salcedo Village, P.O. Box 2108 MCC, MAKATI,
Metro MANILA, Tel. +63 2 816 6380, Fax. +63 2 817 3474

Poland: Ul. Lukiska 10, PL 04-123 WARSZAWA,
Tel. +48 22 612 2831, Fax. +48 22 612 2327

Portugal: see Spain

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Russia: Philips Russia, Ul. Usatcheva 35A, 119048 MOSCOW,
Tel. +7 095 755 6918, Fax. +7 095 755 6919

Singapore: Lorong 1, Toa Payoh, SINGAPORE 1231,
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South Africa: S.A. PHILIPS Pty Ltd., 195-215 Main Road Martindale,
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Tel. +27 11 470 5911, Fax. +27 11 470 5494

South America: Al. Vicente Pinzon, 173, 6th floor,
04547-130 SÃO PAULO, SP, Brazil,
Tel. +55 11 821 2333, Fax. +55 11 821 2382

Spain: Balmes 22, 08007 BARCELONA,
Tel. +34 3 301 6312, Fax. +34 3 301 4107

Sweden: Kottbygatan 7, Akalla, S-16485 STOCKHOLM,
Tel. +46 8 632 2000, Fax. +46 8 632 2745

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Tel. +41 1 488 2686, Fax. +41 1 481 7730

Taiwan: Philips Semiconductors, 6F, No. 96, Chien Kuo N. Rd., Sec. 1,
TAIPEI, Taiwan Tel. +886 2 2134 2865, Fax. +886 2 2134 2874

Thailand: PHILIPS ELECTRONICS (THAILAND) Ltd.,
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Tel. +66 2 745 4090, Fax. +66 2 398 0793

Turkey: Talatpasa Cad. No. 5, 80640 GÜLTEPE/ISTANBUL,
Tel. +90 212 279 2770, Fax. +90 212 282 6707

Ukraine: PHILIPS UKRAINE, 4 Patrice Lumumba str., Building B, Floor 7,
252042 KIEV, Tel. +380 44 264 2776, Fax. +380 44 268 0461

United Kingdom: Philips Semiconductors Ltd., 276 Bath Road, Hayes,
MIDDLESEX UB3 5BX, Tel. +44 181 730 5000, Fax. +44 181 754 8421

United States: 811 East Arques Avenue, SUNNYVALE, CA 94088-3409,
Tel. +1 800 234 7381

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Tel. +381 11 625 344, Fax. +381 11 635 777

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International Marketing & Sales Communications, Building BE-p,
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微波光电部专业代理经销高频、微波、光纤、光电元器件、组件、部件、模块、整机；电磁兼容元器件、材料、设备；微波 CAD、EDA 软件、开发测试仿真工具；微波、光纤仪器仪表。欢迎国外高科技微波、光纤厂商将优秀产品介绍到中国、共同开拓市场。长期大量现货专业批发高频、微波、卫星、光纤、电视、CATV 器件：晶振、VCO、连接器、PIN 开关、变容二极管、开关二极管、低噪晶体管、功率电阻及电容、放大器、功率管、MMIC、混频器、耦合器、功分器、振荡器、合成器、衰减器、滤波器、隔离器、环行器、移相器、调制解调器；光电子器件和组件：红外发射管、红外接收管、光电开关、光敏管、发光二极管和发光二极管组件、半导体激光二极管和激光器组件、光电探测器和光接收组件、光发射接收模块、光纤激光器和光放大器、光调制器、光开关、DWDM 用光发射和接收器件、用户接入系统光收发器件与模块、光纤连接器、光纤跳线/尾纤、光衰减器、光纤适配器、光隔离器、光耦合器、光环行器、光复用器/转换器；无线收发芯片和模组、蓝牙芯片和模组。

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传真：0755-83376182 (0) 13823648918 MSN: SUNS8888@hotmail.com

邮编：518033 E-mail:szss20@163.com QQ: 195847376

深圳赛格展销部：深圳华强北路赛格电子市场 2583 号 电话：0755-83665529 25059422

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TEL: 021-28311762 56703037 13701955389 FAX: 021-56703037

西安分公司：西安高新开发区 20 所(中国电子科技集团导航技术研究所)

西安劳动南路 88 号电子商城二楼 D23 号

TEL: 029-81022619 13072977981 FAX:029-88789382